

# Supporting Information

## Pd-Functionalized ZnO:Eu Columnar Films for Room Temperature Hydrogen Gas Sensing: A Combined Experimental and Computational Approach

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## Supporting Information Text S1

The overview spectra corresponding to ZnO:Eu columnar thin films with increased Eu-doping concentration are shown in **Figure S1a**. For both spectra the presence of Zn, Eu, O and C is clearly observed and the direct comparison indicates that the signal corresponding to Eu is stronger for the ZnO:Eu(4) thin film (blue line, top) than the ZnO:Eu(2) thin film (red line, bottom). The signal corresponding to Zn, Eu and O is attributed to the thin film while the signal of C originates from surface adsorbates such as atmospheric carbohydrates. For a more detailed comparison of the two ZnO:Eu thin films, the C-1s, Eu-3d and Zn-2p lines are depicted in **Figure S1b**. The different level of doping reflects on the europium signal and accordingly the corresponding Eu-3d lines are more pronounced for the ZnO:Eu(4) thin film than for the ZnO:Eu(2) thin film. However, the peak position of the Eu-3d<sub>5/2</sub> and Eu-3d<sub>3/2</sub> lines are identical for both thin films. The location of the Eu-3d<sub>5/2</sub> line centred around 1134.6 eV corresponds well with Eu<sup>3+</sup> in Eu<sub>2</sub>O<sub>3</sub> <sup>1</sup>. In contrast, for metallic Eu a peak located around 1126 eV is typically reported <sup>2</sup>. Accordingly, in the europium doped ZnO thin films the Eu is most likely present as Eu<sup>3+</sup> like in Eu<sub>2</sub>O<sub>3</sub>. The closer evaluation of the Zn-2p lines yields information about the oxidation state of Zn in the ZnO:Eu thin films. For both thin films, the Zn-2p<sub>3/2</sub> line is located with a peak around 1021.7 eV, which corresponds well with Zn<sup>2+</sup> in ZnO (commonly reported between 1021.40 eV and 1022.50 eV) <sup>1</sup>.

In order to indicate the doping level in both thin films with increased Eu-doping, an exemplary quantification was conducted. The quantification of the europium doped ZnO thin films was performed based on the Zn-2p and Eu-3d lines (see **Figure S1b**) for the sample ZnO:Eu(4)

and ZnO:Eu(2). The Eu/Zn ratio in this XPS spectra quantification is roughly 1.11 and 0.67 respectively, which in turn corresponds to a Eu- doping surface concentration of about 53 % in case of ZnO:Eu(4) and 40 % in case of ZnO:Eu(2). Some details on sample SCS preparation can be found in other work too <sup>3-4</sup>.

### Supporting Information Text S2

After surface relaxation, the top and bottom surfaces were not equivalent and therefore we also needed to consider the unrelaxed surface energy ( $\gamma_u$ ) in order to calculate the final surface energy of the relaxed surface. The unrelaxed surface energy is defined as the surface energy before any surface optimization and is calculated as:

$$\gamma_u = \frac{E_{slab,u} - nE_{bulk}}{2A} \quad (1)$$

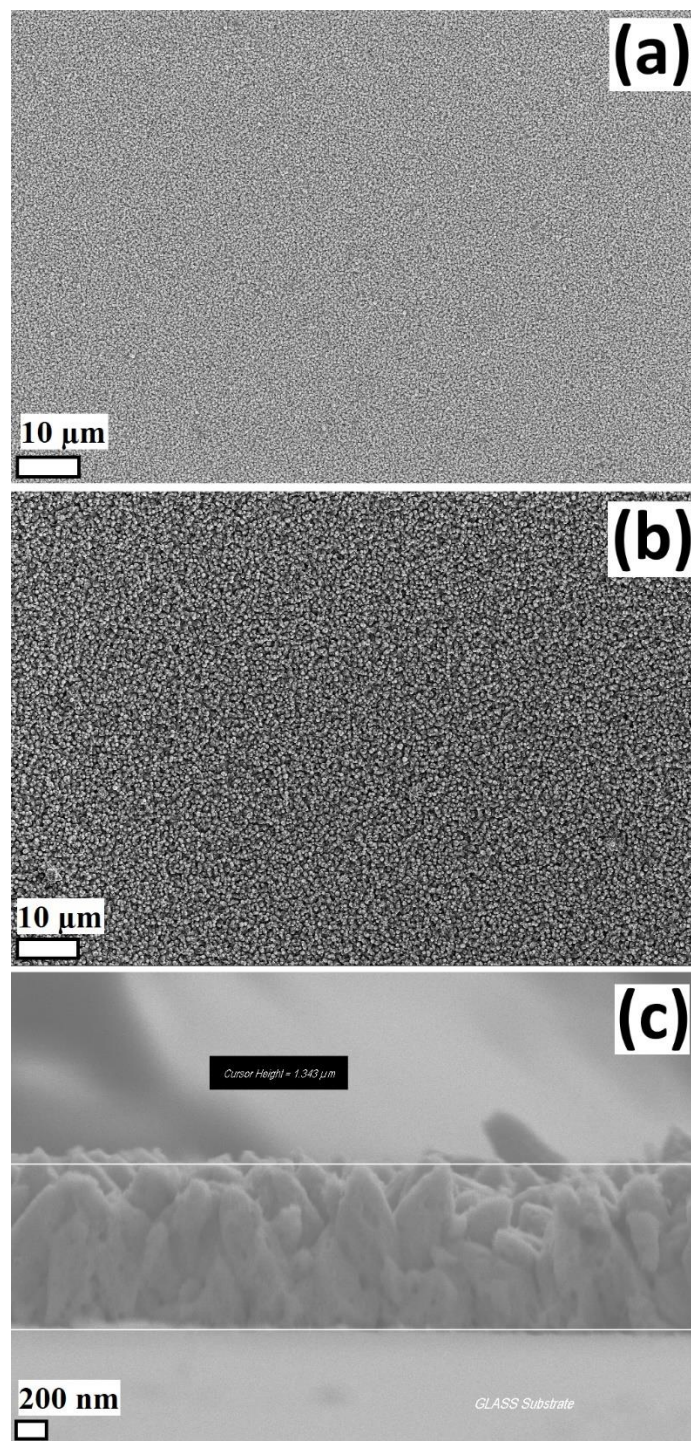
where  $E_{slab,u}$  is the energy of the unrelaxed slab,  $nE_{bulk}$  is the energy of an equal number of bulk atoms, and  $A$  is the surface area of one side of the slab. Using this value, it is then possible to calculate the relaxed surface energy ( $\gamma_r$ ) from the total energy of the relaxed slab.

The relaxed surface energy,  $\gamma_r$ , is given by:

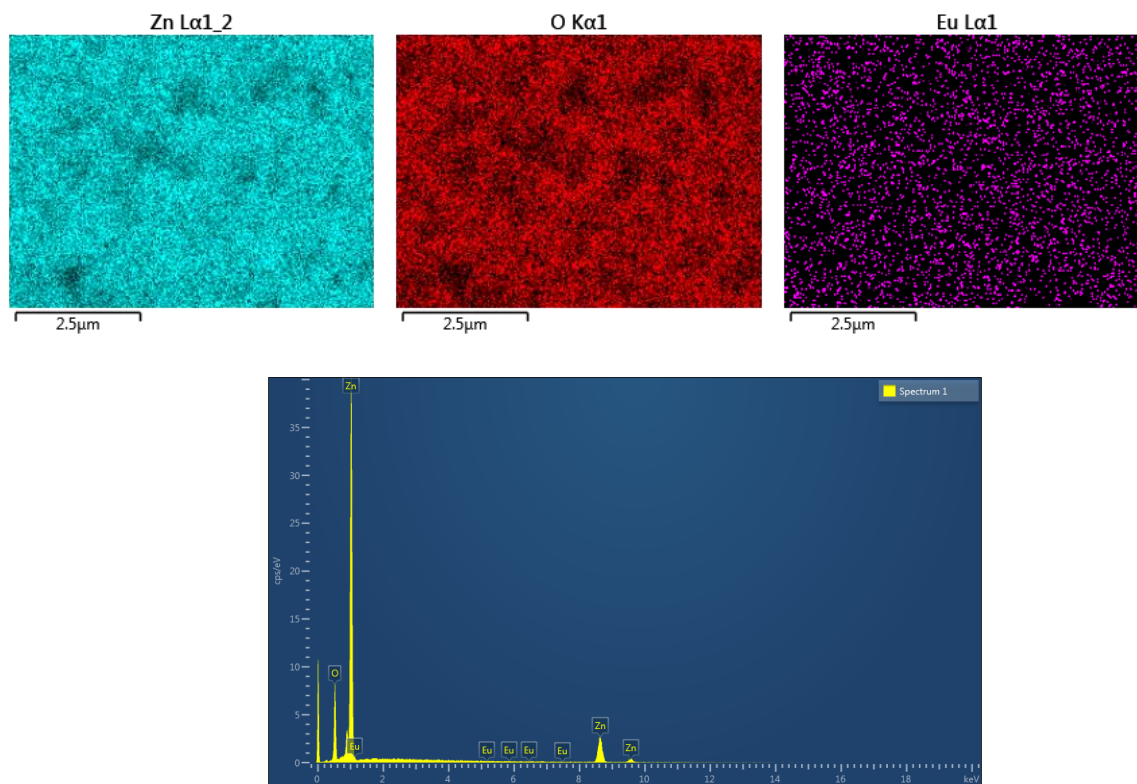
$$\gamma_r = E_{slab,r} - nE_{bulk} - \gamma_u \quad (2)$$

where  $E_{slab,r}$  is the energy of the relaxed slab.

Bader charges were calculated using a developed by Henkelman and co-workers <sup>5-6</sup>.



**Figure S1.** SEM images of ZnO:Eu films thermal annealed at: (a) 650 °C for 2 h, with about 0.1 at. % Eu; (b) 650 °C for 2 h with about 0.15 at% Eu and Pd-functionalized; (c) 650 °C for 2 h with about 0.2 at. % Eu in sectional-view showing a thickness of about 1.35  $\mu\text{m}$ .



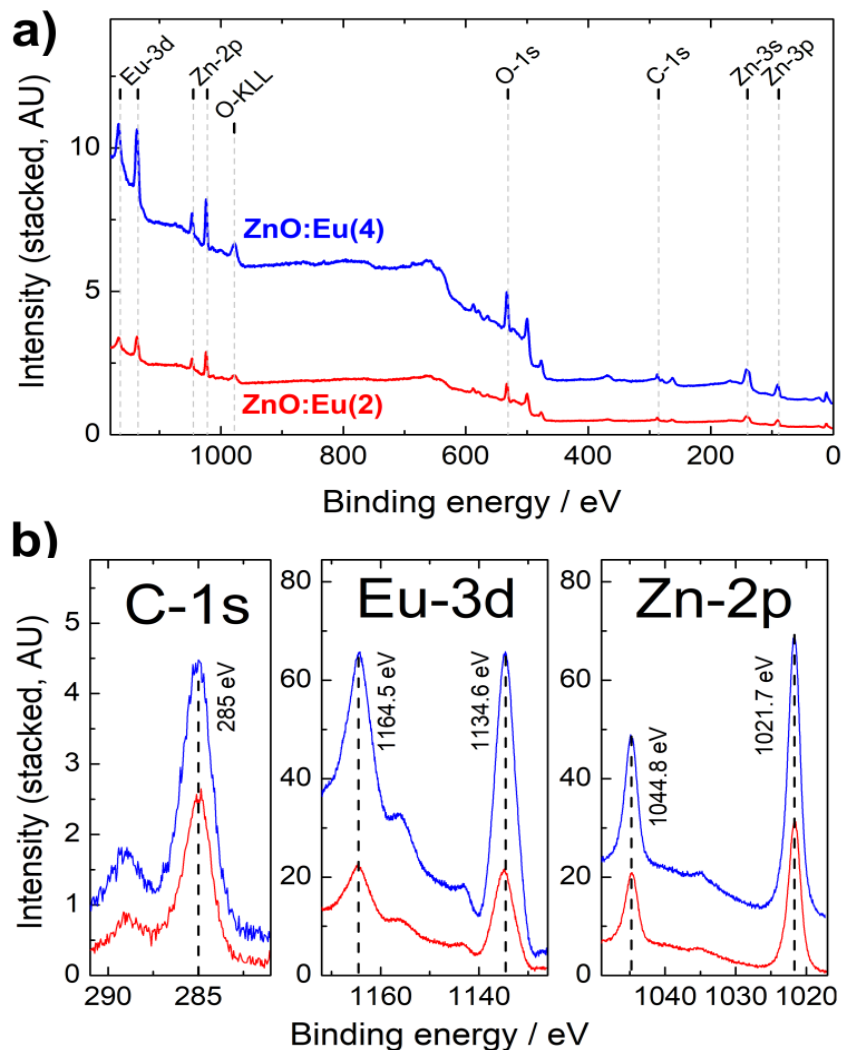
Sample ZnO:Eu<sub>2</sub>T<sub>650</sub>C

Result Type	Atomic %
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Spectrum Label	Spectrum 1
O	49.30
Zn	50.60
Eu	0.10
Total	100.00

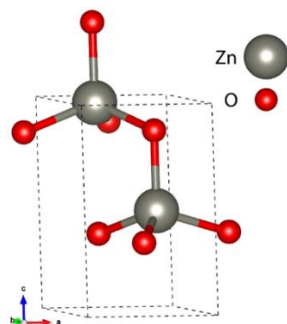
Statistics	O	Zn	Eu
Max	49.30	50.60	0.10
Min	49.30	50.60	0.10
Average	49.30	50.60	0.10
Standard Deviation	0.00	0.00	0.00

**Figure S2.** Compositional images taken by EDX elemental mapping at the microstructural level of columnar ZnO:Eu<sub>2</sub> films thermal annealed at 650 °C for 2 h, with about 0.1 at. % Eu and EDX spectra below, respectively.

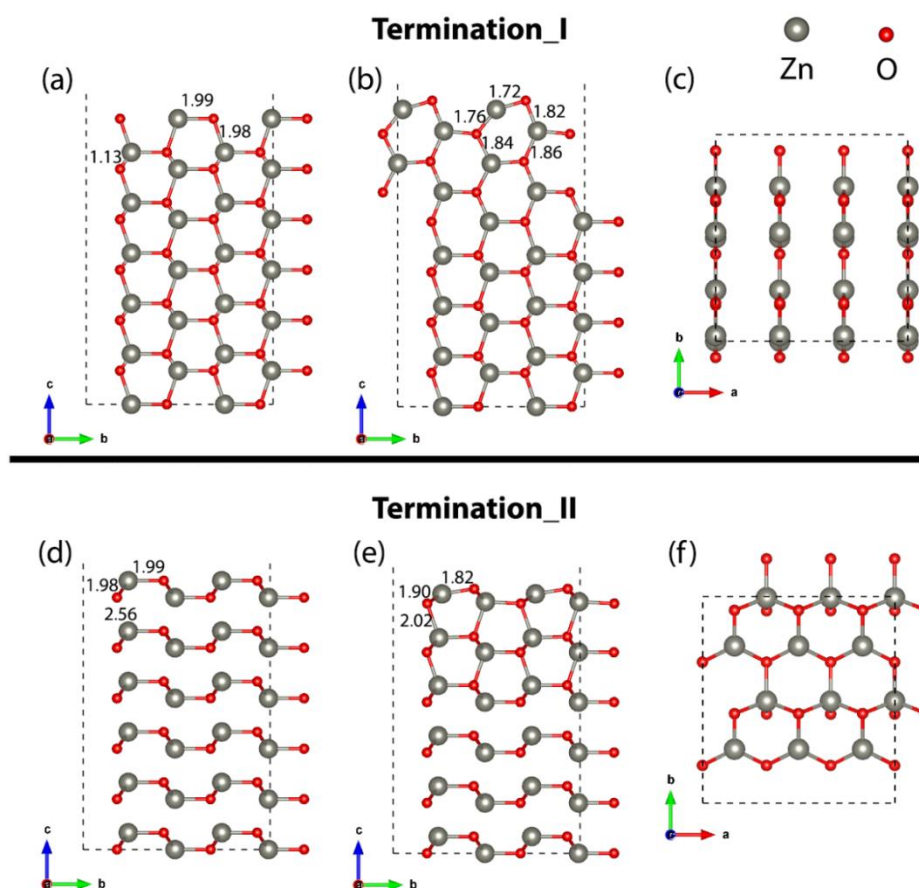


**Figure S3.** XPS spectra of ZnO:Eu columnar thin films with different doping concentrations. The overview spectra (a) reveal the presence of Eu, Zn, O and C for both ZnO:Eu thin films. The high resolution spectra (b) of the C-1s line, Eu-3d lines and Zn-2p lines indicate that there is no difference in peak positions between both samples. The peak location of Eu-3d and Zn-2p lines correspond to  $\text{Eu}^{3+}$  in  $\text{Eu}_2\text{O}_3$  and  $\text{Zn}^{2+}$  in ZnO respectively.

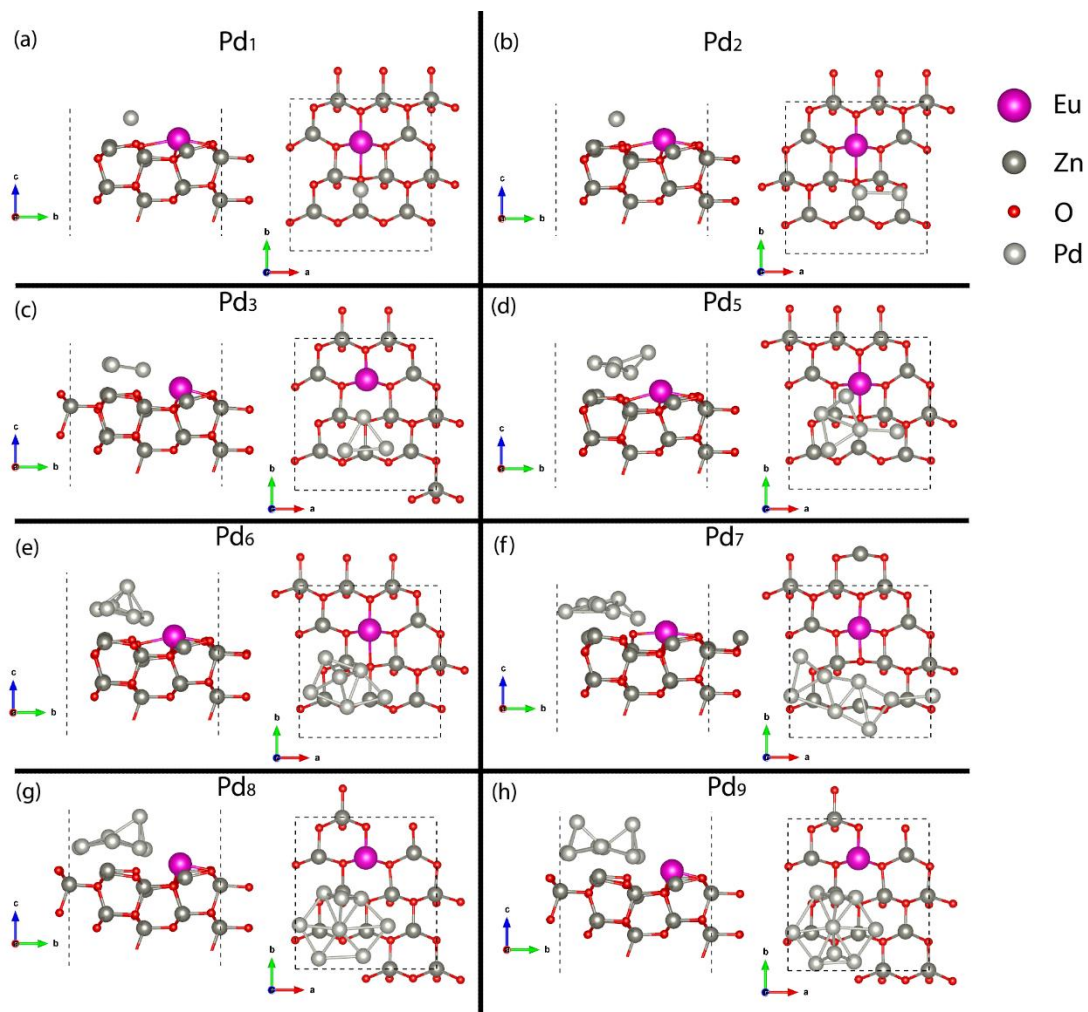




**Figure S4.** Bulk structure of ZnO.



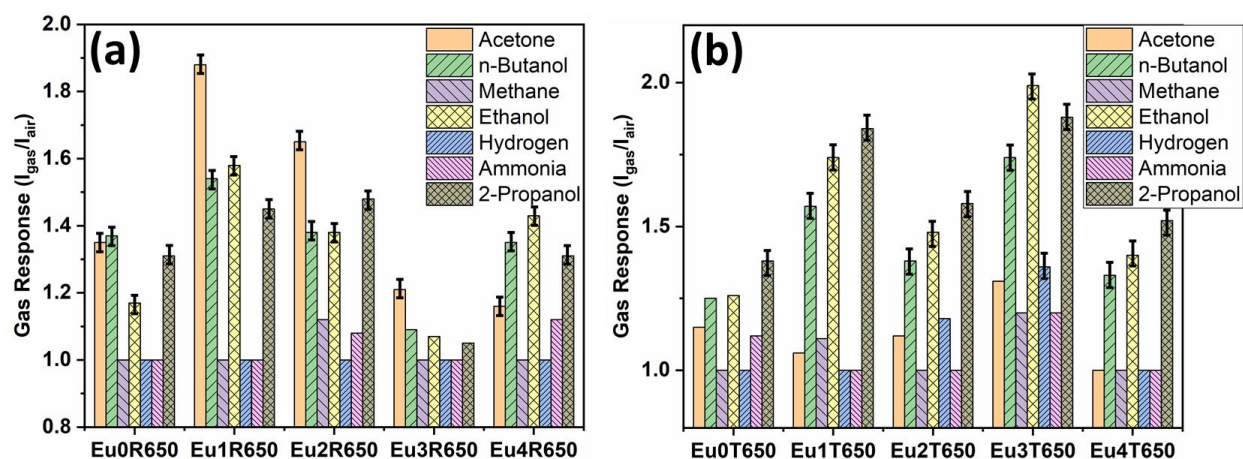
**Figure S5.** Two possible ZnO ( $1\ 0\ \bar{1}\ 0$ ) surface terminations. (a, b, and c): Termination\_I (side view of un-relaxed structure, side view of relaxed structure, and top view of relaxed structure. (d, e, and f): Termination\_II (side view of un-relaxed structure, side view of relaxed structure, and top view of relaxed structure.



**Figure S6.** Top and side views of  $\text{Pd}_n$  ( $n=1$  to  $9$ ) clusters adsorbed on  $\text{Eu:ZnO}(10\bar{1}0)$  surface:

(a, b, c, d):  $\text{Pd}_1$ ,  $\text{Pd}_2$ ,  $\text{Pd}_3$  and  $\text{Pd}_5$  cluster over  $\text{Eu:ZnO}(10\bar{1}0)$  surface. (e, f, g, h):  $\text{Pd}_5$ ,  $\text{Pd}_6$ ,  $\text{Pd}_7$ ,  $\text{Pd}_8$ , and  $\text{Pd}_9$  cluster over  $\text{Eu:ZnO}(10\bar{1}0)$  surface.

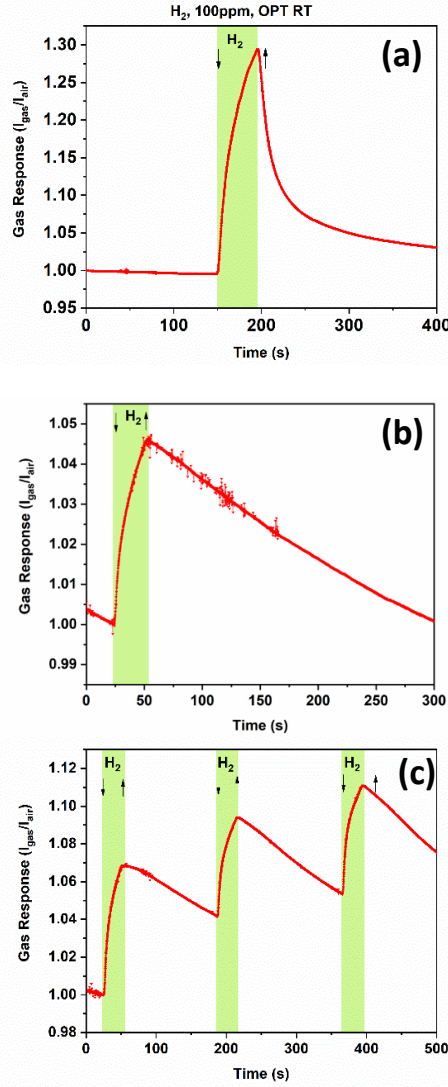




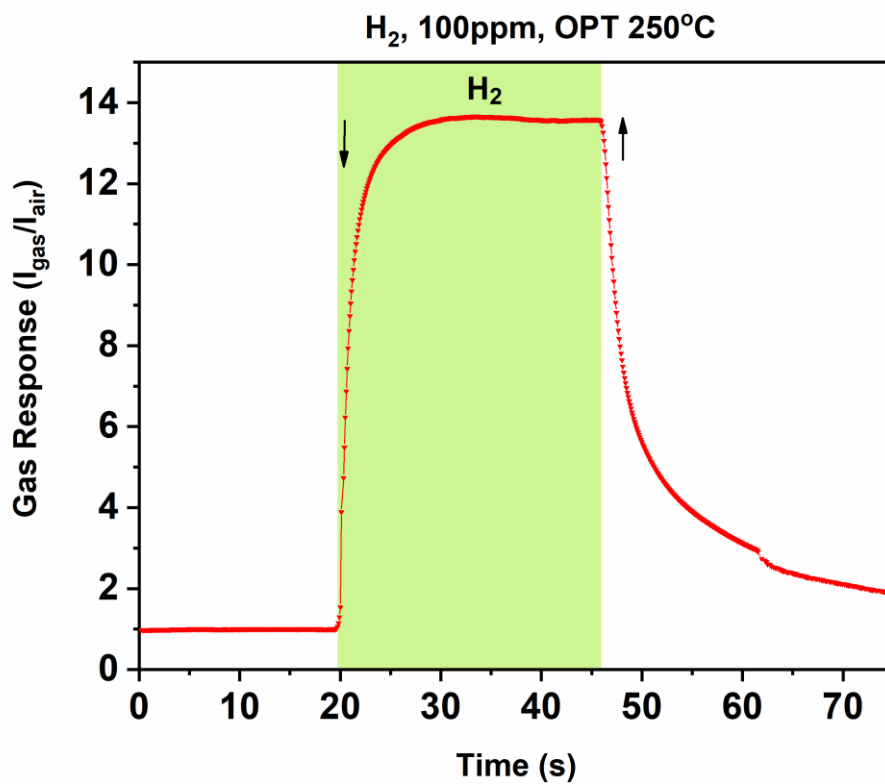
**Figure S7.** The gas response of pristine ZnO:Eu columnar films with different content of Eu (0.00 at. % Eu – Eu0; ~0.05 at. % Eu – Eu1; ~0.10 at. % Eu – Eu2; ~0.15 at. % Eu – Eu3 and ~0.20 at. % Eu – Eu4) to 100 ppm of different gases at operating temperature of 350 °C: (a) samples RTA-treated at 650 °C for 60 s; and (b) samples TA-treated at 650 °C for 2 h.

**Figure S7a** presents the gas response of pristine ZnO:Eu columnar films RTA-treated at 650 °C for 60 s and with different content of Eu (0.00 at. % Eu noted as Eu0; ~0.05 at. % Eu noted as Eu1; ~0.10 at. % Eu noted as Eu2; ~0.15 at. % Eu noted as Eu3 and ~0.20 at. % Eu noted as Eu4) to 100 ppm of different gases at operating temperature of 350 °C. **Figure S7b** presents the gas response of sample sets with different content of Eu as noted above, but TA-treated at 650 °C for 2 h. It can be clearly seen that at higher operating temperature (350 °C) both types of annealed sample sets do not show selectivity and proves that sensor function is perfect at 350 °C.

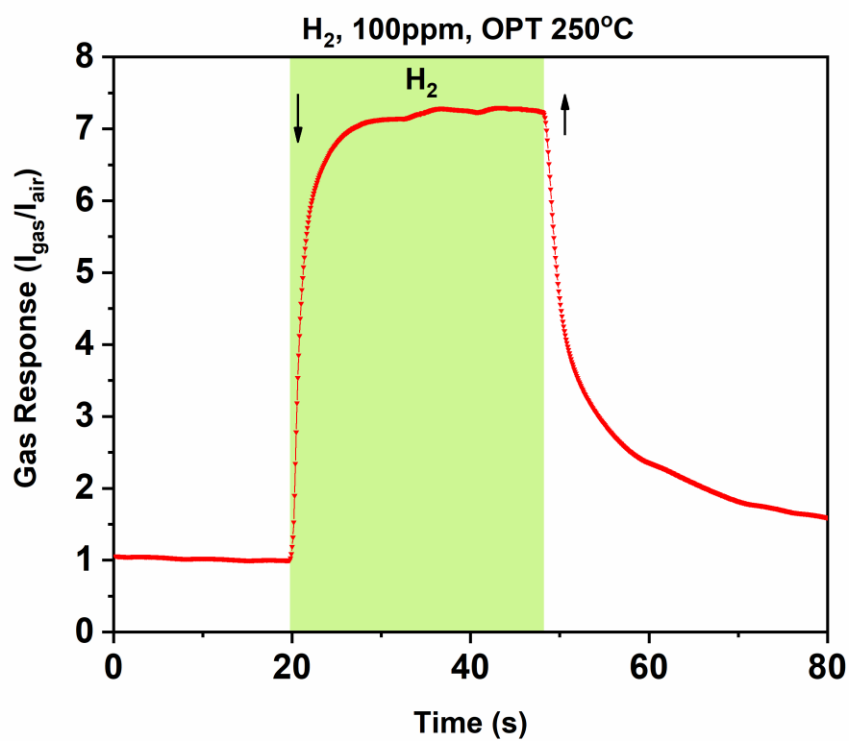
**Figure S8** shows dynamic response of Pd-functionalized ZnO:Eu columnar films for 100, 200 and 300 ppm of hydrogen measured at room temperature. It clearly proves that by Eu-doping of columnar ZnO films followed by Pd-functionalization it is possible to decrease the operating temperature of the sensing material versus H<sub>2</sub> gas.



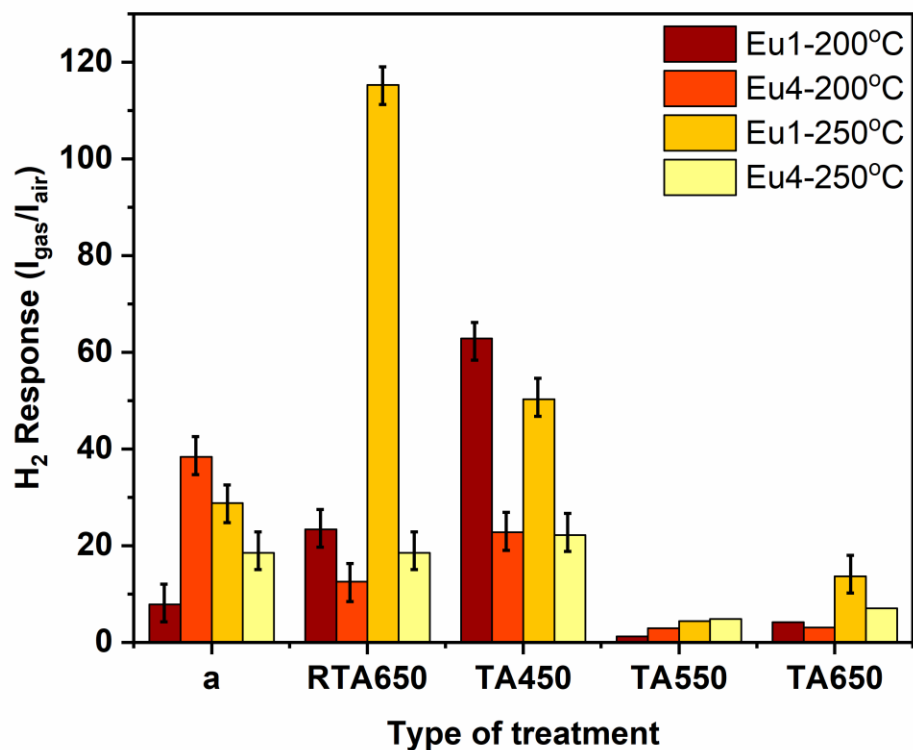
**Figure S8.** Dynamic response of Pd-functionalized ZnO:Eu columnar films for: (a) 100 ppm of hydrogen measured at room temperature; (b) 200 ppm of hydrogen measured at room temperature, sample with 0.05 at. % Eu subjected to TA550, sample set Eu1T550; (c) 300 ppm of hydrogen measured at room temperature, sample with 0.1 at. % Eu after TA550.



**Figure S9.** Dynamic response of ZnO with about 0.05 at. % Eu – Eu1T650; Pd-functionalized columnar films for 100 ppm of hydrogen gas at operating temperature of 250 °C.



**Figure S10.** Dynamic response of ZnO:Eu with about 0.2 at. % Eu –Eu4T650; Pd-functionalized columnar films for 100 ppm of hydrogen gas at operating temperature of 250 °C.



**Figure S11.** Response of Pd-functionalized ZnO:Eu columnar films to 100 ppm hydrogen versus treatment type (TA or RTA), noted as Eu1( ~0.05 at. % Eu), Eu4(~0.2 at. % Eu) at operating temperatures of 200 °C and 250 °C. Type of treatment: **a** - as grown; RTA650-rapid thermal annealing; TA450,TA550,TA650 - thermal annealing at 450, 550, 650 °C, respectively.

**Table S1.** Calculated adsorption energies ( $E_{\text{ads}}$ ) (in eV), shortest Pd-Zn ( $d_{\text{Zn}}^{\text{s}}$ ) and Pd-O ( $d_{\text{O}}^{\text{s}}$ ) distances (in Å) of the  $\text{Pd}_n$  cluster with the first atomic layer of the ZnO slab for different  $\text{Pd}_n/\text{ZnO}$  ( $10\bar{1}0$ ) systems.

	$\text{Pd}_1$	$\text{Pd}_2$	$\text{Pd}_3$	$\text{Pd}_5$	$\text{Pd}_6$	$\text{Pd}_7$	$\text{Pd}_8$	$\text{Pd}_9$
$E_{\text{ads}}$	-1.65	-2.89	-5.35	-6.97	-7.05	-6.98	-7.83	-8.15
$d_{\text{Zn}}^{\text{s}}$	2.533	2.542	2.657	2.543	2.627	2.641	2.679	2.635
$d_{\text{O}}^{\text{s}}$	2.149	2.168	2.218	2.101	2.109	2.101	2.063	2.061



## References

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